

High Power Diode Hockey Puk Version R750 B...C Series

Types : R750 B 320 to R750 B 440

FEATURES

- Wide current range
- High voltage ratings up to 4400 V
- High surge current capabilities
- Case style DO- 200AB (B-PUK)

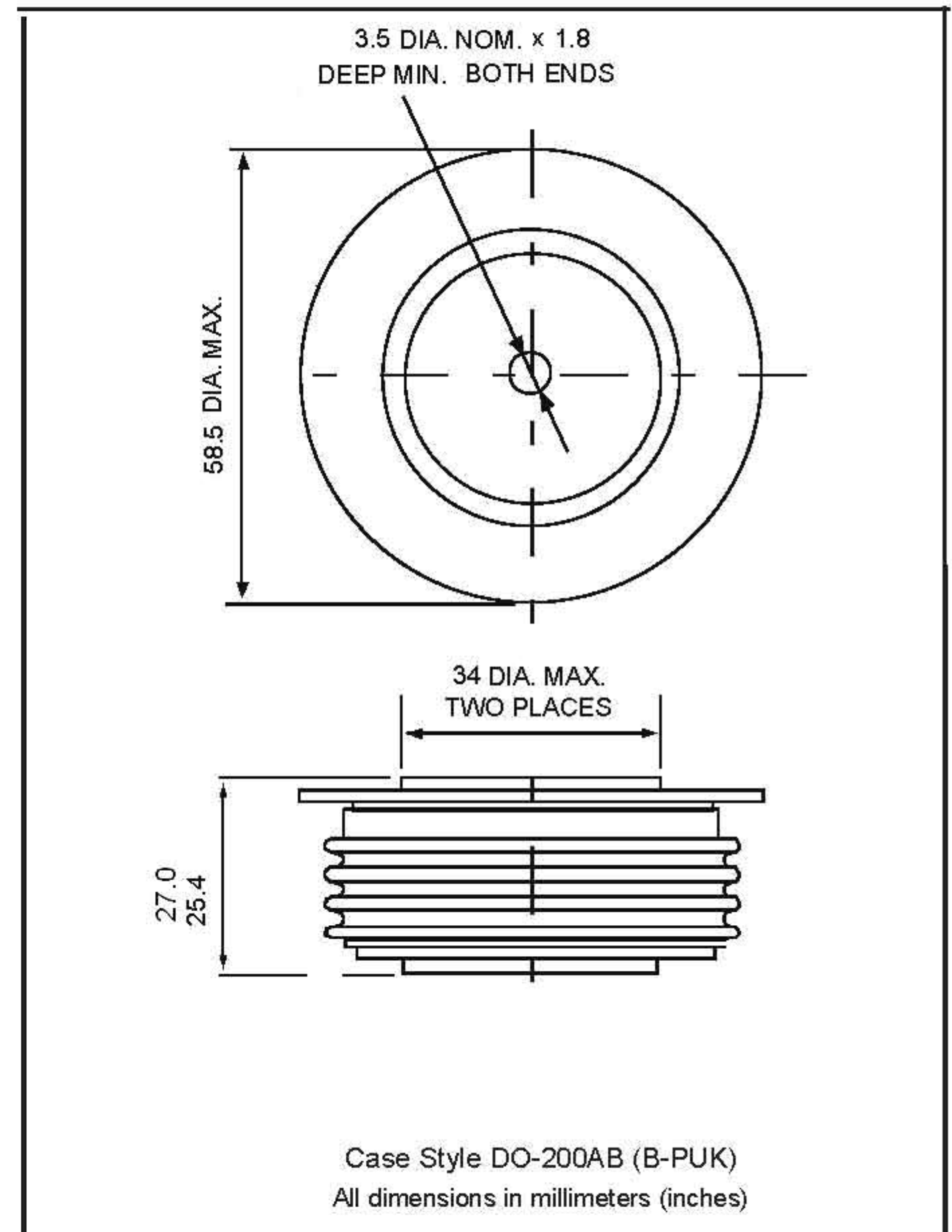
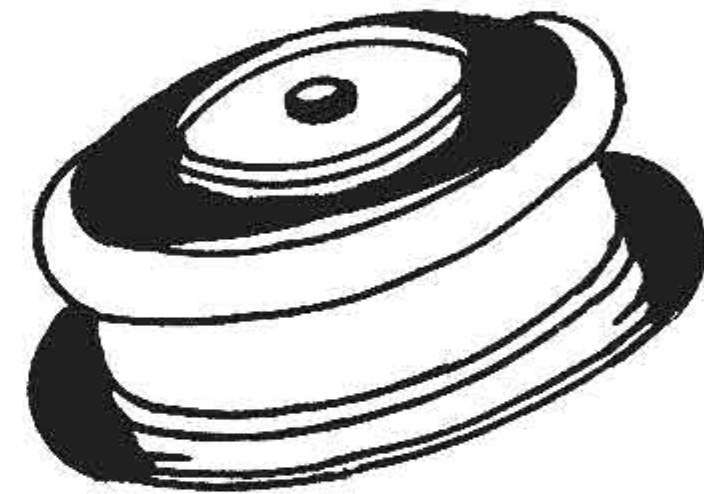
TYPICAL APPLICATIONS

- Converters
- High power drives
- Power supplies
- Traction Application

MAJOR RATINGS & CHARACTERISTICS

Parameters	R750 B	Units	
$I_{F(AV)}$	750	A	
@ T_{hs}	85	°C	
$I_{F(RMS)}$	1177	A	
@ T_{hs}	85	°C	
I_{FSM}	@ 50 Hz	10	KA
I^2t	@ 50 Hz	500	KA ² s
V_{RRM} range	3200 to 4400	V	
T_J	-40 to 160	°C	

R750 B (B - PUK)



High Power Diode Hockey Puk Version R750 B...C Series

Type: R750B...32C to R750B...44C

FEATURES

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- ▣ High voltage ratings up to 4400 V
- ▣ High surge current capabilities
- ▣ Case style DO- 200AB (B-PUK)

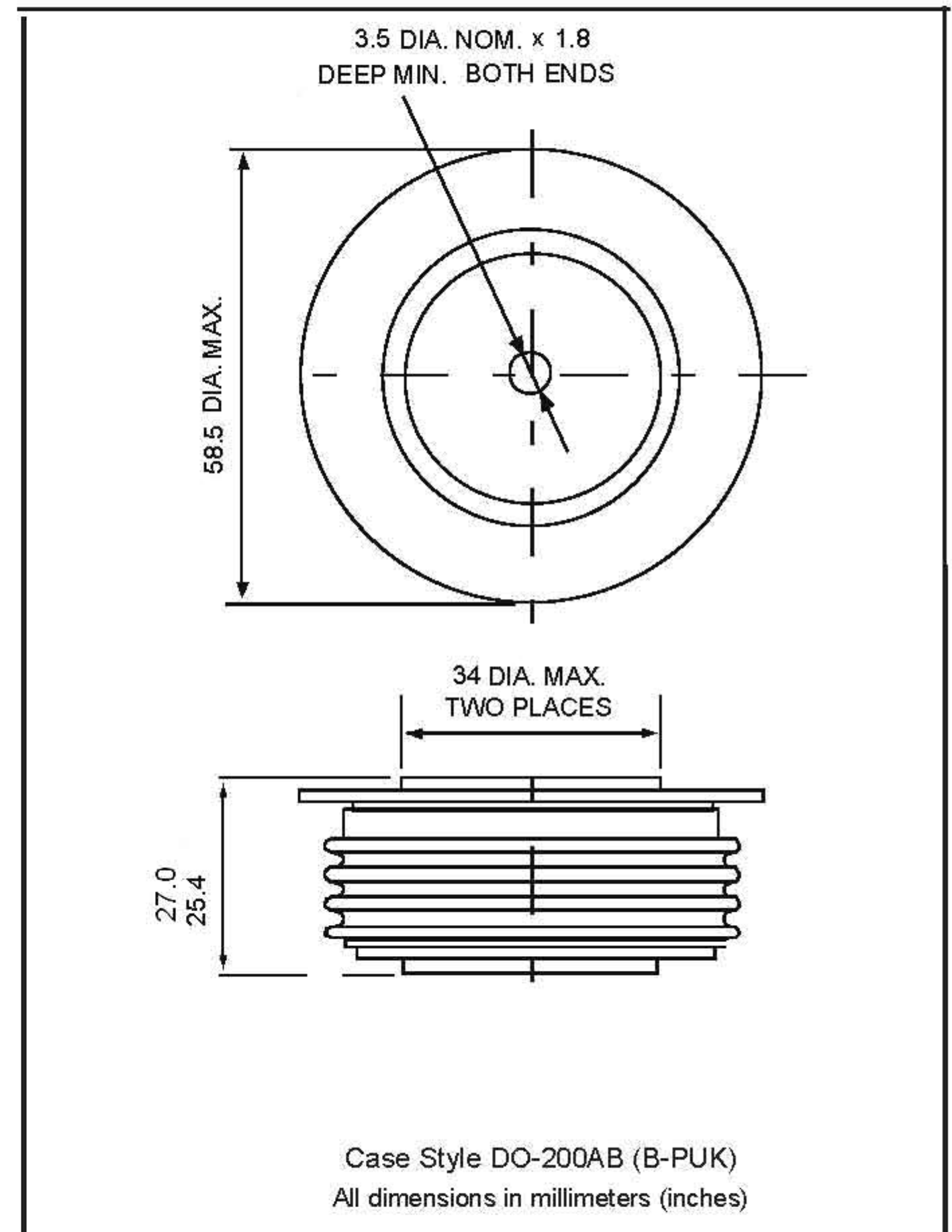
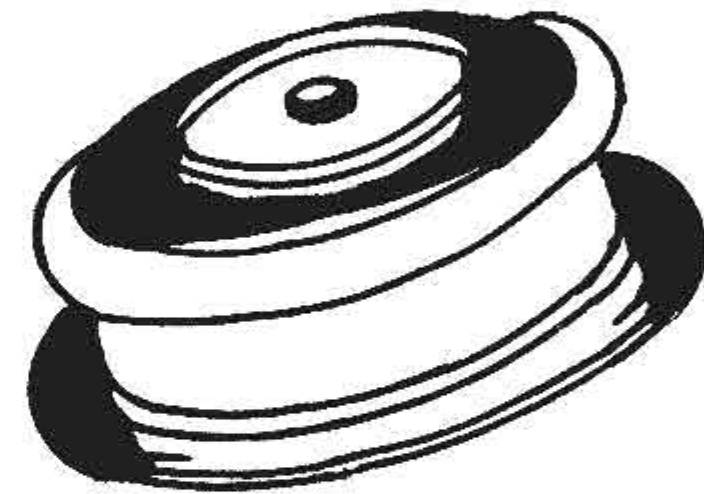
TYPICAL APPLICATIONS

- ▣ Converters
- ▣ High power drives
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- ▣ Traction Application

MAJOR RATINGS & CHARACTERISTICS

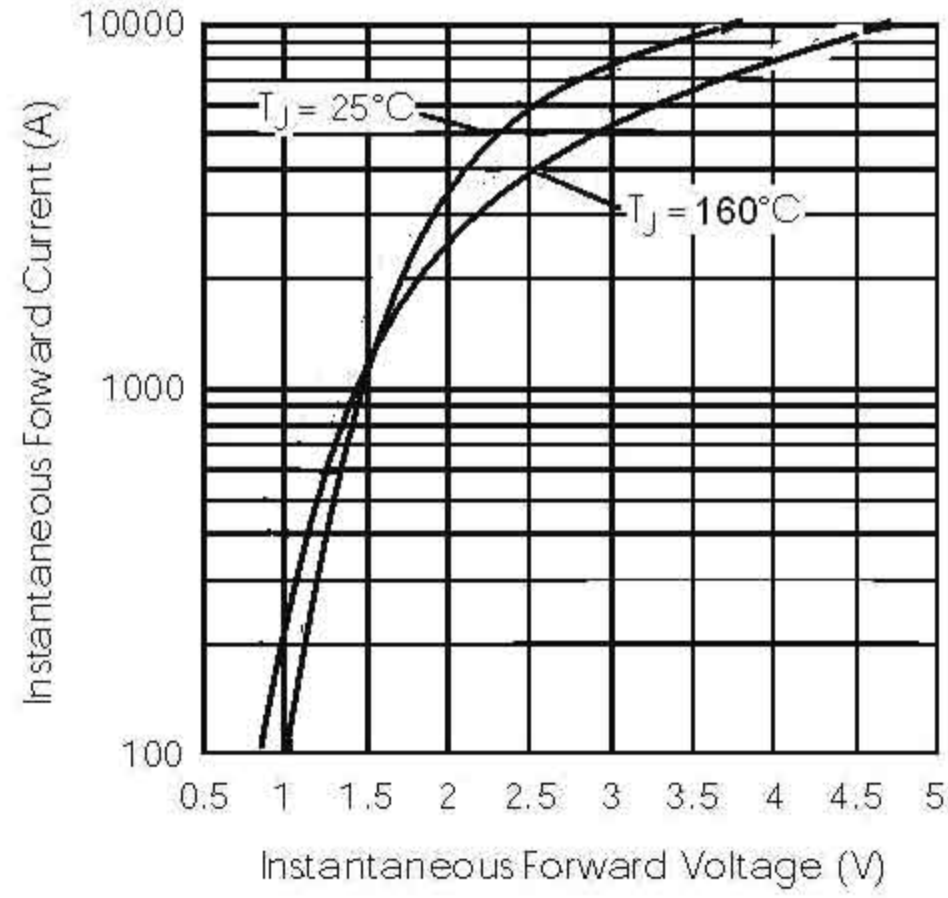
Parameters	R750 B	Units	
$I_{F(AV)}$	750	A	
@ T_{hs}	85	°C	
$I_{F(RMS)}$	1177	A	
@ T_{hs}	85	°C	
I_{FSM}	@ 50 Hz	10	KA
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V_{RRM} range	3200 to 4400	V	
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R750 B (B - PUK)

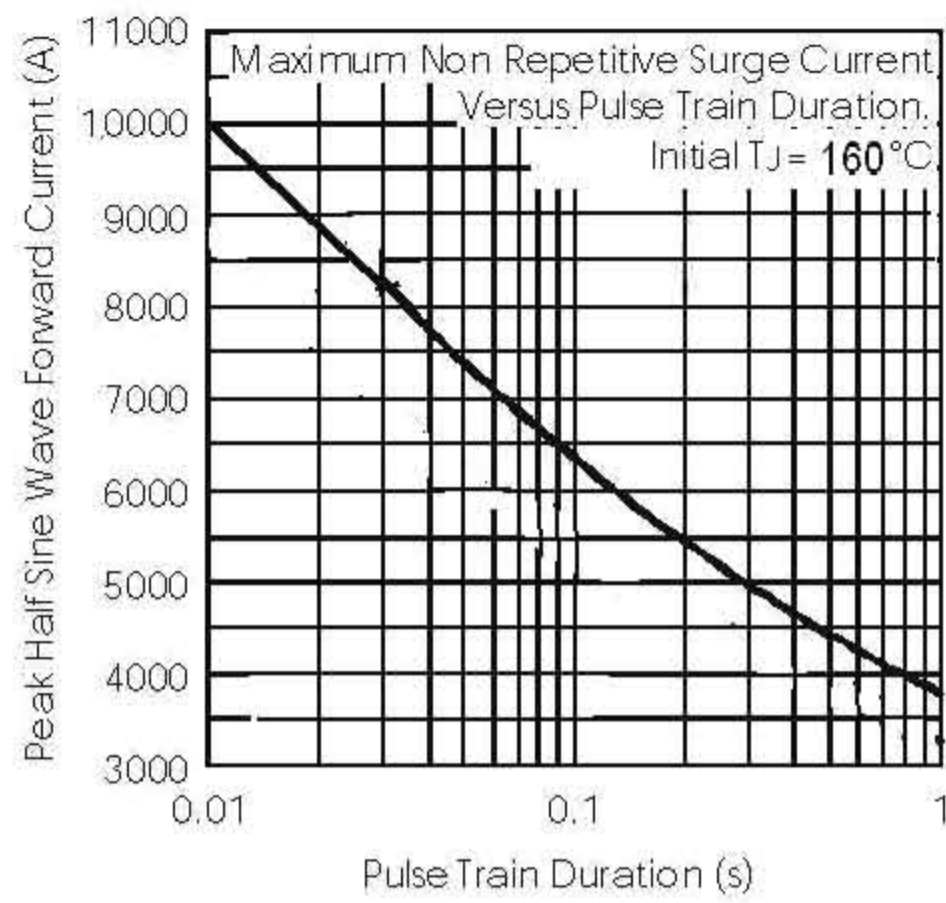


STANDARD RECOVERY DIODES

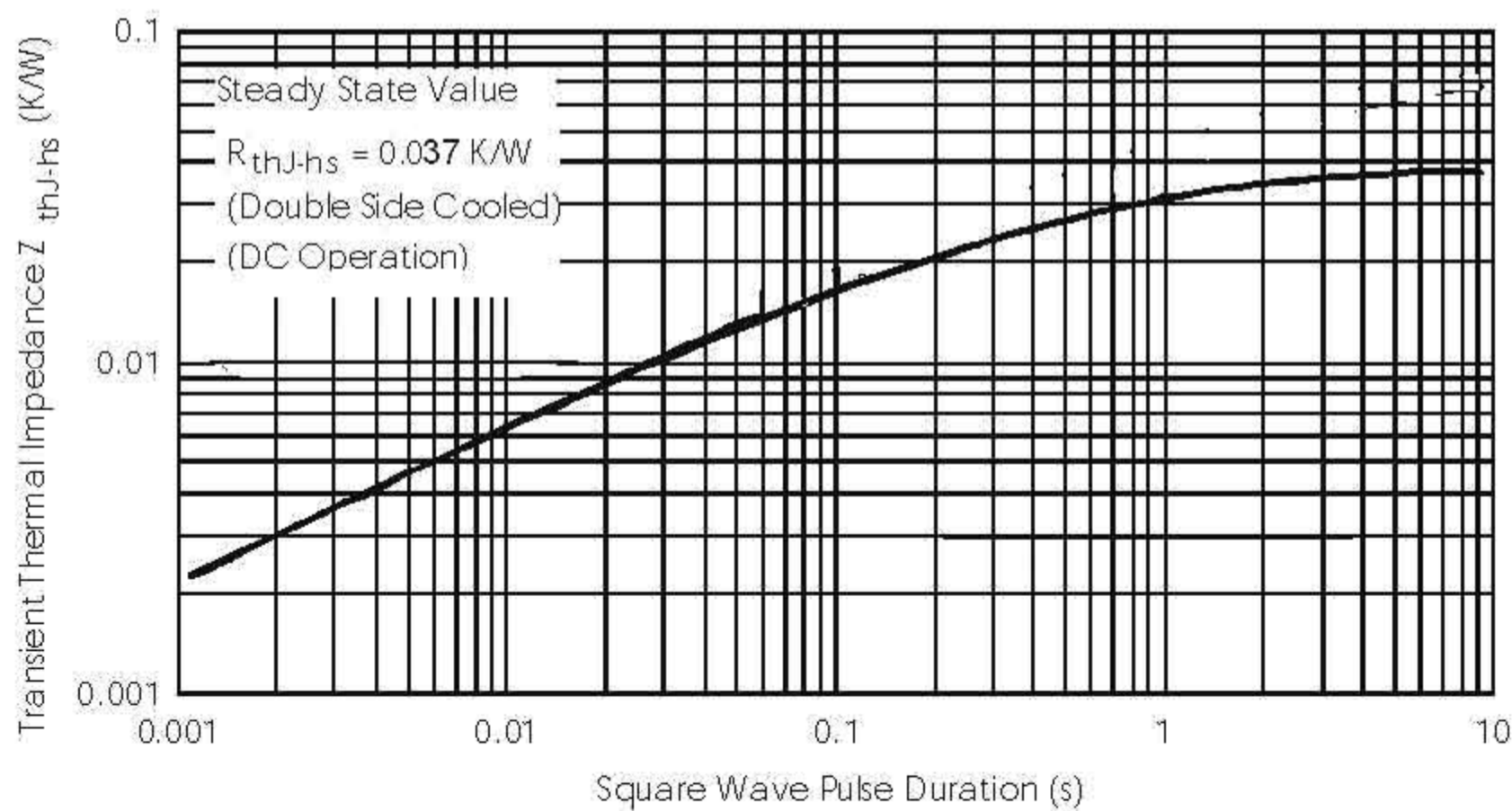
R750B...C Series



Forward Voltage Drop Characteristics



Maximum Non-Repetitive Surge Current
Double Side Cooled



Thermal Impedance Z_{thJc} Characteristics

STANDARD RECOVERY DIODES

R750 B

ELECTRICAL SPECIFICATION VOLTAGE RATINGS

Type Number	Voltage Code	V_{RRM} , max. repetitive peak reverse voltage V	V_{RRM} , max. non-repetitive peak reverse voltage V	I_{DRM} max. @ $T_J = T_J$ max. mA
R750 B	320	3200	3250	50
	340	3400	3450	
	360	3600	3650	
	380	3800	3850	
	400	4000	4050	
	420	4200	4250	
	440	4400	4250	

FORWARD CONDUCTION

	Parameter	R750 B	Units	Conditions
$I_{F(AV)}$	Max. average Forward current @ heat sink temperature	750	A	180° conduction, half sine wave double side cooled
		85	°C	
$I_{F(RMS)}$	Max. RMS Forward current	1177		@85°C heat sink temperature (double side cooled)
I_{FSM}	Max. peak one cycle Forward non-repetitive surge current	10	KA	t = 10ms Sinusoidal half wave,
I^2t	Maximum I^2t for fusing	500	kA ² s	t = 10ms Initial $T_J = T_J$ max.
$I^2\sqrt{t}$	Maximum $I^2\sqrt{t}$ for fusing	5000	kA ² √s	t = 0.1 to 10ms. No voltage reapplied.
V_O	Threshold voltage	0.80	V	$T_J = T_J$ max.
r_o	Slope resistance	1.0	mΩ	$T_J = T_J$ max.
V_{FM}	Max. Forward voltage drop	1.45	V	$I_{pk} = 1000A$, $T_J = T_J$ max., $t_p = 10ms$ sine pulse

THERMAL AND MECHANICAL SPECIFICATION

	Parameter	R750 B	Units	Conditions
T_J	Max. operating temperature range	-40 to 160	°C	
T_{stg}	Max. storage temperature range	-55 to 170		
R_{thJ-hs}	Max. thermal resistance, junction to heat sink	0.037	K/W	DC operation double side cooled
F	Mounting force, ±10%	14700 (1500)	N (kg)	
w t	Approximate weight	255	g	
	Case style	DO-200AB(B-PUK)		See outline